

Surface mount diode

Fast silicon rectifier diodes

SA 261...265

Forward Current: 2 A

Reverse Voltage: 1200 to 2000 V

Features

- Max. solder temperature: 260°C
- Plastic material has UL classification 94V-0

Mechanical Data

- Plastic case Melf / DO-213AB
- Weight approx.: 0,12 g
- Terminals: plated terminals solderable per MIL-STD-750
- Mounting position: any
- Standard packaging: 5000 pieces per reel

1) Max. temperature of the terminals $T_T = 100\text{ °C}$

2) $I_F = 2\text{ A}$, $T_A = 25\text{ °C}$

3) $T_A = 25\text{ °C}$

4) Mounted on P.C. board with 50 mm² copper pads at each terminal

Type	Polarity color band	Repetitive peak reverse voltage V_{RRM} V	Surge peak reverse voltage V_{RSM} V	Maximum forward voltage $T_j = 25\text{ °C}$ $I_F = 2\text{ A}$ $V_F^{(2)}$ V	Maximum reverse recovery time $I_F = 0,5\text{ A}$ $I_R = 1\text{ A}$ $I_{RR} = 0,25\text{ A}$ t_{rr} ns
SA 261	-	1200	1200	1,8	500
SA 262	-	1400	1400	1,8	500
SA 263	-	1600	1600	1,8	500
SA 264	-	1800	1800	1,8	500
SA 265	-	2000	2000	1,8	500

Absolute Maximum Ratings

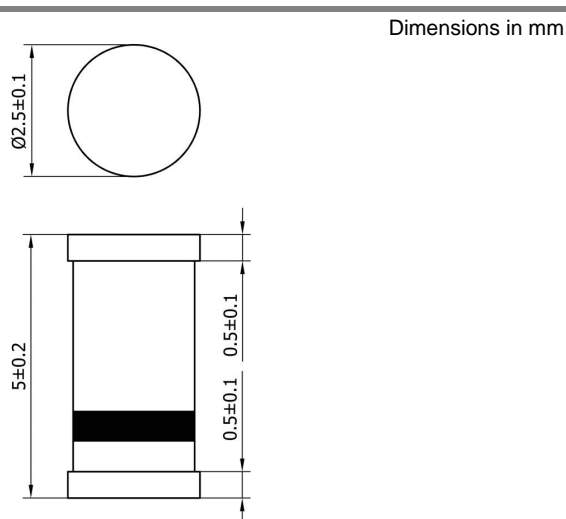
$T_c = 25\text{ °C}$, unless otherwise specified

Symbol	Conditions	Values	Units
I_{FAV}	Max. averaged fwd. current, R-load, $T_T = 100\text{ °C}$	2	A
I_{FRM}	Repetitive peak forward current $f > 15\text{ Hz}^1)$	10	A
I_{FSM}	Peak fwd. surge current 60 Hz half sinus-wave ³⁾	50	A
I^2t	Rating for fusing, $t < 10\text{ ms}^3)$	12,5	A ² s
R_{thA}	Max. thermal resistance junction to ambient ⁴⁾	45	K/W
R_{thT}	Max. thermal resistance junction to terminals	15	K/W
T_j	Operating junction temperature	-50...+175	°C
T_s	Storage temperature	-50...+175	°C

Characteristics

$T_c = 25\text{ °C}$, unless otherwise specified

Symbol	Conditions	Values	Units
I_R	Maximum leakage current, $T_j = 25\text{ °C}$; $V_R = V_{RRM}$ $T_j = 100\text{ °C}$; $V_R = V_{RRM}$	<5 <100	μA μA
C_j	Typical junction capacitance (at MHz and applied reverse voltage of V)	-	pF
Q_{rr}	Reverse recovery charge ($U_R = V$; $I_F = A$; $dI_F/dt = A/ms$)	-	μC
E_{RSM}	Non repetitive peak reverse avalanche energy ($I_R = mA$; $T_j = \text{°C}$; inductive load switched off)	-	mJ



case : Melf / DO-213AB

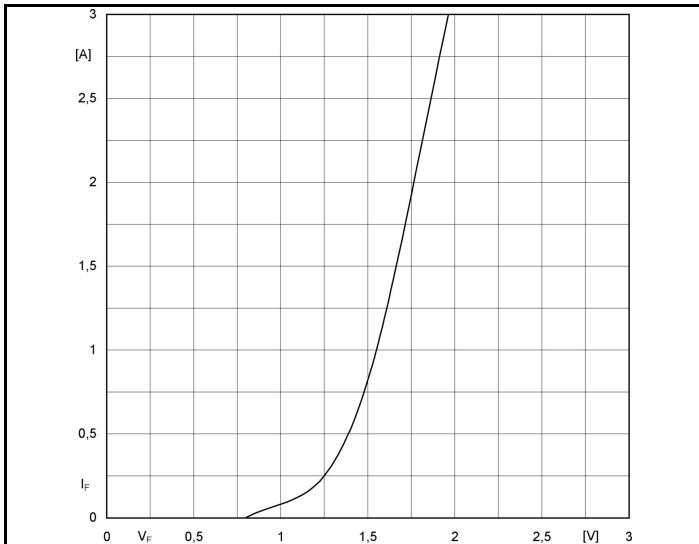


Fig. 1 Forward characteristics (typical values)

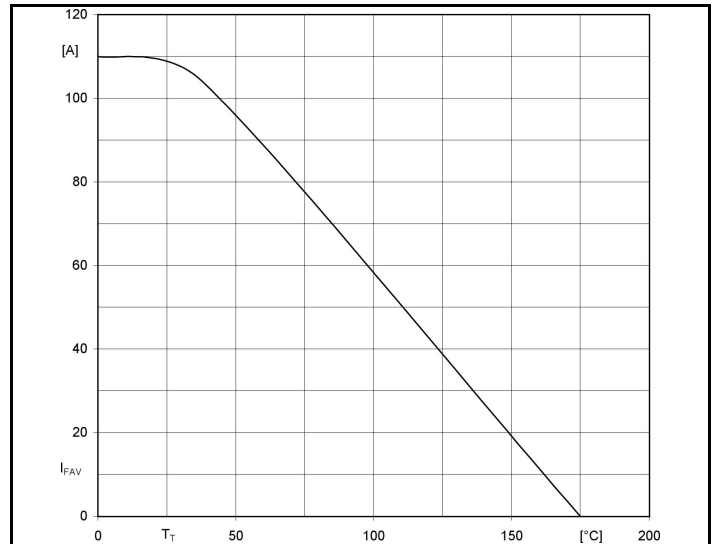


Fig. 2 Rated forward current vs. ambient temperature ⁴⁾